

TLP361J

Triac Drivers
 Programmable Controllers
 AC-Output Modules, Solid State Relays

TOSHIBA TLP361J consists of a zero-voltage-crossing turn-on photo-triac optically coupled to a gallium arsenide infrared-emitting diode in a four-lead plastic DIP package.

- Peak off-state voltage: 600 V (min)
- Trigger LED current: 10 mA (max)
- On-state current: 100 mA (max)
- Isolation voltage: 5000 Vrms (min)
- Zero crossing Function
- UL approved: UL1577, File No.E67349
- cUL approved :CSA Component Acceptance Service No. 5A, File No.E67349
- CQC approved:GB4943.1,GB8898 Japan Factory
- Option (D4) VDE approved : DIN EN60747-5-5 ,EN60065,EN60950-1 (Note1) EN62368-1(Pending) (Note1)

(Note 1) : When a EN60747-5-5 approved type is needed, please designate “Option(D4)”

Maximum operating insulation voltage : 890 Vpk
 Maximum permissible overvoltage : 8000 Vpk

•Construction mechanical rating

	7.62 mm pitch TLPXXX type	10.16 mm pitch TLPXXXF type
Creepage distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation thickness	0.4 mm (min)	0.4 mm (min)

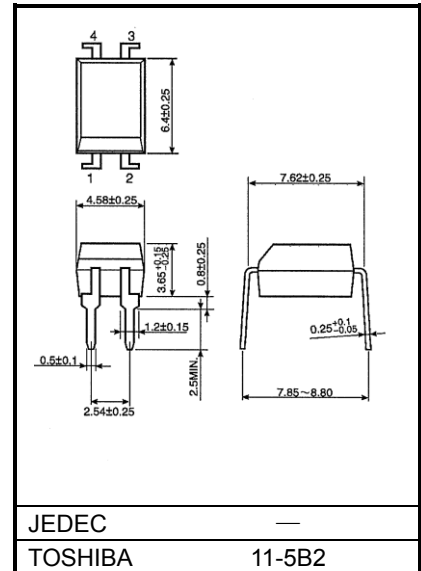
•Trigger LED current

Classification*	Trigger LED current (mA)		Marking of classification
	VT=3V, Ta=25°C		
	Min	Max	
(IFT7)		7	T7
Standard	—	10	T7, blank

*Example: “(IFT7)”; “TLP361J(IFT7)”

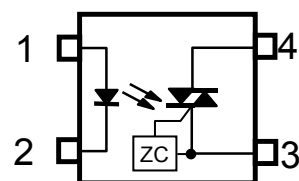
(Note) When specifying the application type name for certification testing, be sure to use the standard product type name, e.g. TLP361J(IFT7): TLP361J

Unit: mm



Weight: 0.26 g (typ.)

Pin Configuration (top view)



- 1: Anode
- 2: Cathode
- 3: Triac Terminal
- 4: Triac Terminal

Start of commercial production
 2003-06

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
LED	Forward current	IF	50	mA	
	Forward current derating (Ta ≥ 53°C)	ΔIF / °C	-0.7	mA / °C	
	Peak forward current (100 μs pulse, 100 pps)	IFP	1	A	
	Reverse voltage	VR	5	V	
	Diode power dissipation	PD	100	mW	
	Diode power dissipation derating (Ta ≥ 53°C)	ΔPD / °C	-1.4	mW / °C	
	Junction temperature	Tj	125	°C	
Detector	Off-state output terminal voltage	VDRM	600	V	
	On-state RMS current	Ta = 25°C	IT(RMS)	100	mA
		Ta = 70°C		50	
	On-state current derating (Ta ≥ 25°C)	ΔIT / °C	-1.1	mA / °C	
	Peak on-state current (100 μs pulse, 120 pps)	ITP	2	A	
	Peak non-repetitive surge current (Pw = 10 ms)	ITSM	1.2	A	
	Output power dissipation	PO	300	mW	
	Output power dissipation derating (Ta ≥ 25°C)	ΔPO / °C	-3.0	mW / °C	
	Junction temperature	Tj	115	°C	
Storage temperature range	Tstg	-55~125	°C		
Operating temperature range	Topr	-40~100	°C		
Lead soldering temperature (10s)	Tsol	260	°C		
Isolation voltage (AC, 1 minute, R.H. ≤ 60%)	(Note 1) BV _S	5000	Vrms		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pins 1 and 2 are shorted together and pins 3 and 4 are shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Supply voltage	V _{AC}	—	—	240	V _{ac}
Forward current	IF	15	20	25	mA
Peak on-state current	ITP	—	—	1	A
Operating temperature	T _{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V_F = 0 \text{ V}, f = 1 \text{ MHz}$	—	30	—	pF
Detector	Peak off-state current	I_{DRM}	$V_{DRM} = 600 \text{ V}$	—	10	1000	nA
	Peak on-state voltage	V_{TM}	$I_{TM} = 100 \text{ mA}$	—	1.7	3.0	V
	Holding current	I_H	—	—	0.6	—	mA
	Critical rate of rise of off-state voltage	dv/dt	$V_{in} = 240 \text{ Vrms}, T_a = 85^\circ\text{C}$ (Note 2)	200	500	—	V/ μs
	Critical rate of rise of commutating voltage	dv/dt(c)	$V_{in} = 60 \text{ Vrms}, I_T = 15 \text{ mA}$ (Note 2)	—	0.2	—	V/ μs

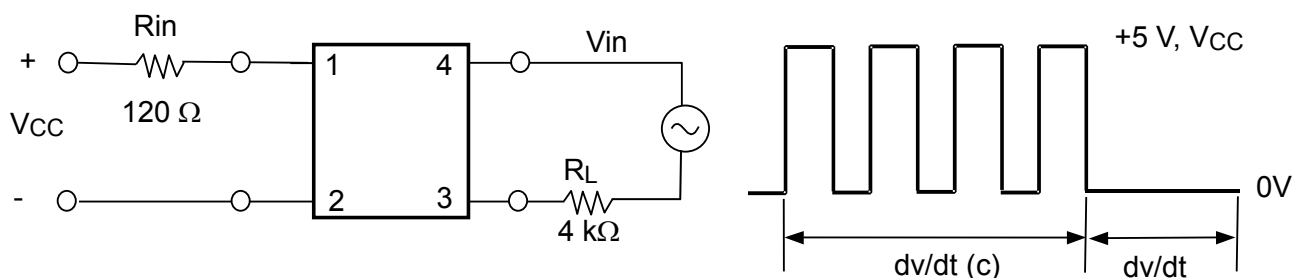
Coupled Electrical Characteristics (Ta = 25°C)

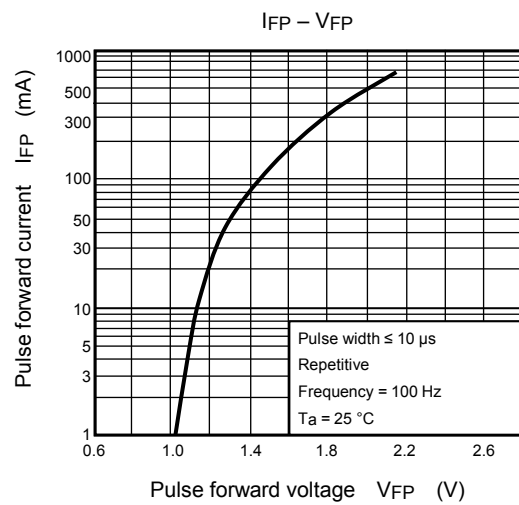
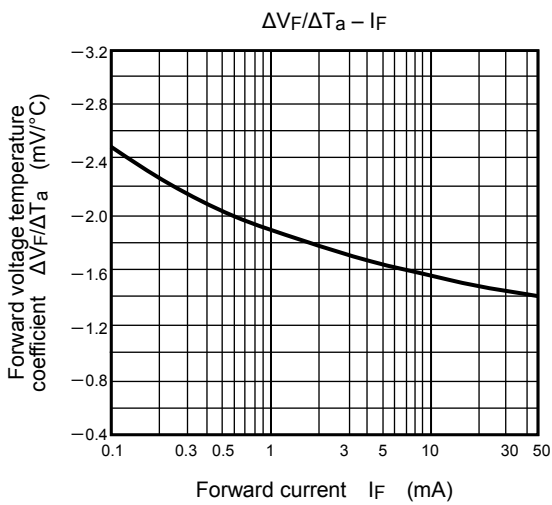
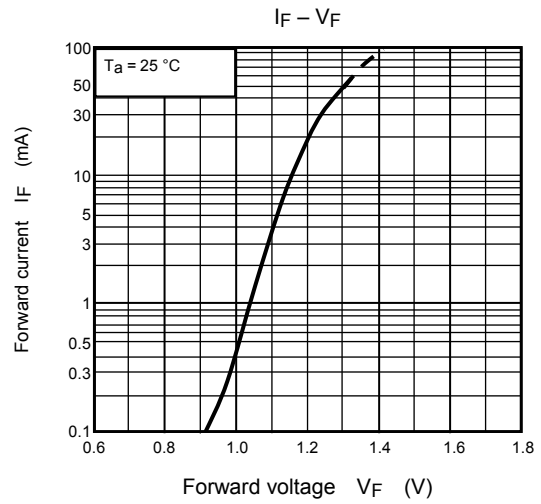
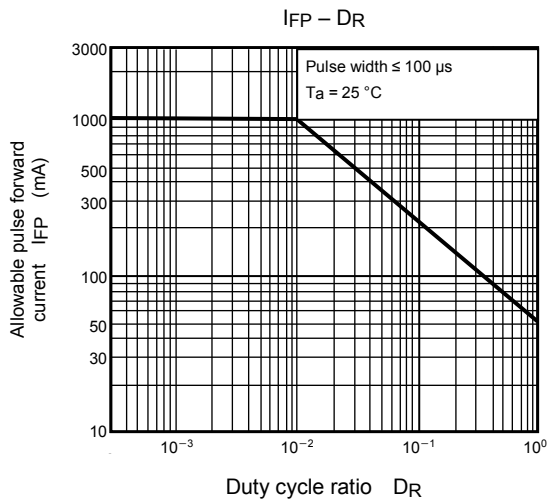
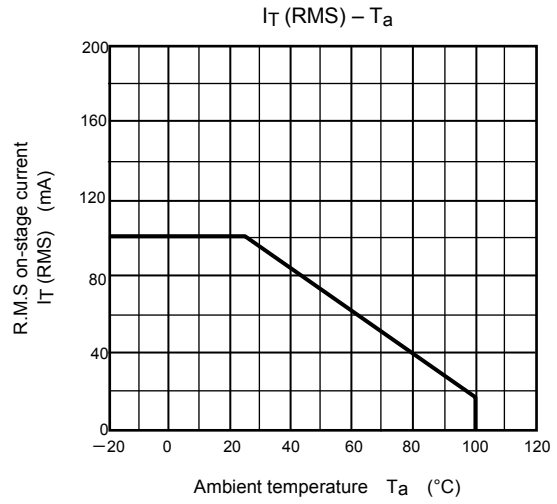
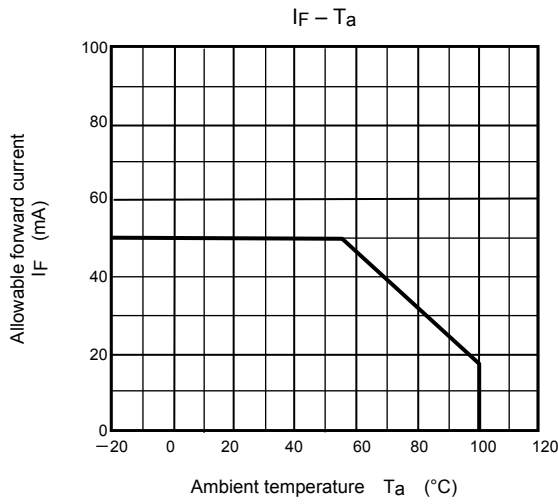
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	I_{FT}	$V_T = 3 \text{ V}$	—	—	10	mA
Inhibit voltage	V_{IH}	$I_F = \text{Rated } I_{FT}$	—	—	20	V
Leakage in inhibited state	I_{IH}	$I_F = \text{Rated } I_{FT}$ $V_T = \text{Rated } V_{DRM}$	—	200	600	μA
Turn-on time	t_{ON}	$V_D = 3 \rightarrow 1.5 \text{ V}, R_L = 20 \Omega$ $I_F = \text{Rated } I_{FT} \times 1.5$	—	30	100	μs

Isolation Characteristics (Ta = 25°C)

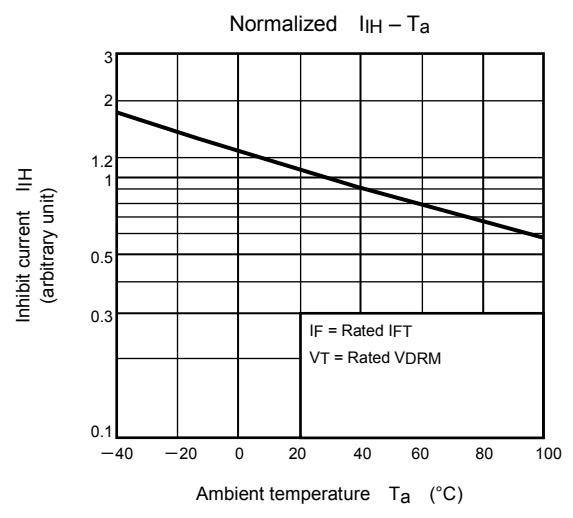
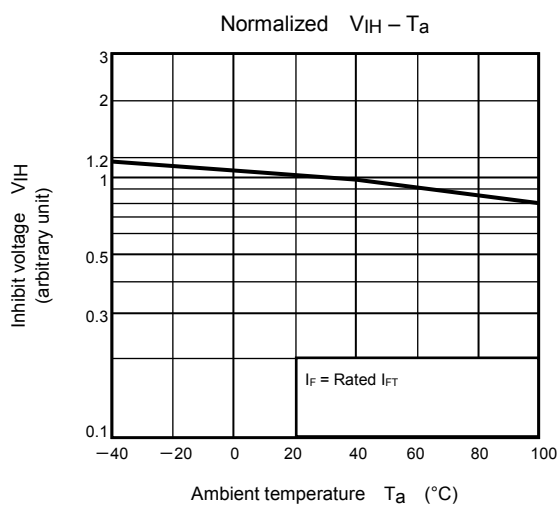
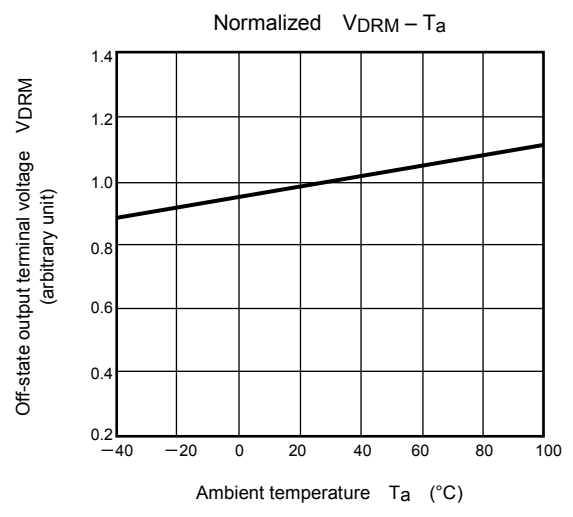
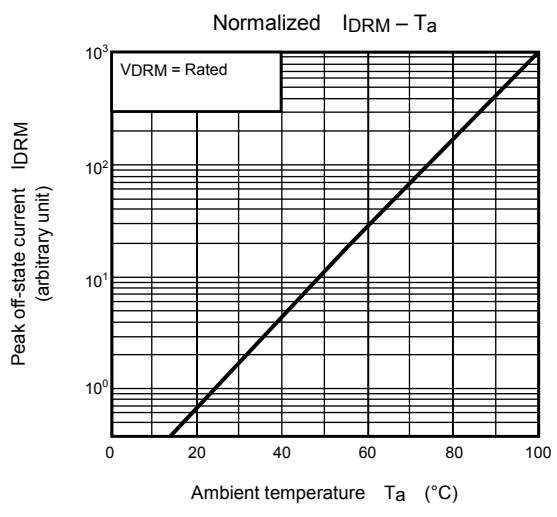
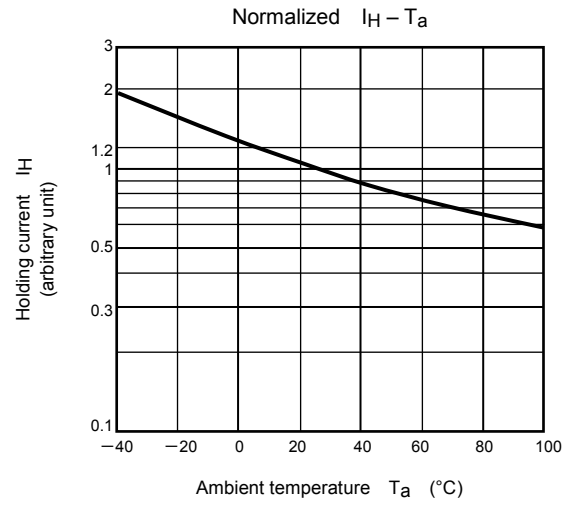
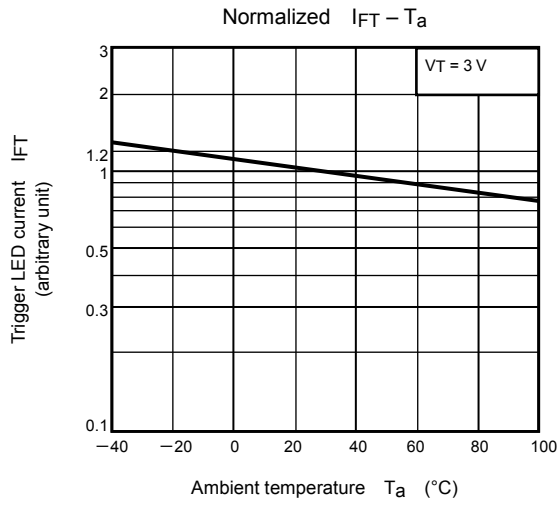
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance (input to output)	C_S	$V_S = 0 \text{ V}, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	B_V	AC, 1 minute	5000	—	—	Vrms
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

(Note 2): dv/dt test circuit





*: The above graphs show typical characteristics.



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